

3.3V Triple and Quad Video Amplifiers

June 2002

FEATURES

- Single Supply Operation from 3V to 12.6V
- Small (3mm × 5mm) MSOP 10-Lead Package
- Internal Resistors for a Gain of Two
- 340V/μs Slew Rate
- 110MHz –3dB Bandwidth
- 30MHz Flat to 0.25dB
- 3% Settling Time: 20ns
- Input Common Mode Range Includes Ground
- Rail-to-Rail Output
- High Output Drive: 60mA
- Operating Temperature Range: –40°C to 85°C
- 15-Bit RGB, 1024 × 768 Resolution

APPLICATIONS

- Automotive Displays
- RGB Amplifiers
- Coaxial Cable Drivers
- Low Voltage High Speed Signal Processing
- Set Top Boxes

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DESCRIPTION

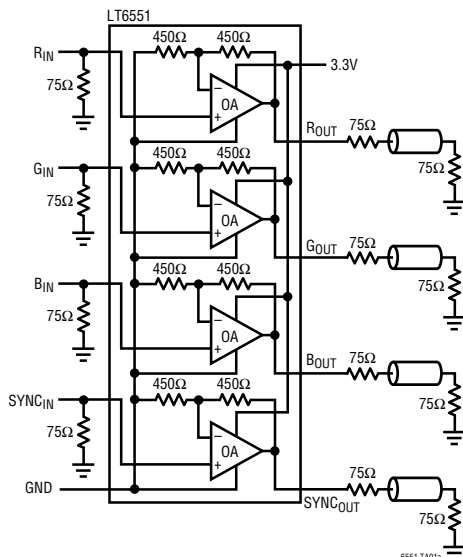
The LT[®]6550/LT6551 are 3.3V triple and quad high speed video amplifiers. These voltage feedback amplifiers drive double terminated 50Ω or 75Ω cables and are configured for a fixed gain of 2, eliminating six or eight external gain setting resistors. The LT6550/LT6551 feature 110MHz –3dB bandwidth, high slew rates and fast settling, making them ideal for RGB video processing.

The LT6551 quad is designed for single supply operation and the LT6550 triple can be used on either single or split supplies. On a single 3.3V supply, the input voltage range extends from ground to 1.55V and the output swings to within 400mV of the supply voltage while driving a 150Ω load. These features, combined with the ability to accept RGB video signals without the need for AC coupling or level shifting of the incoming signals, make the LT6550/LT6551 an ideal choice for low voltage video applications.

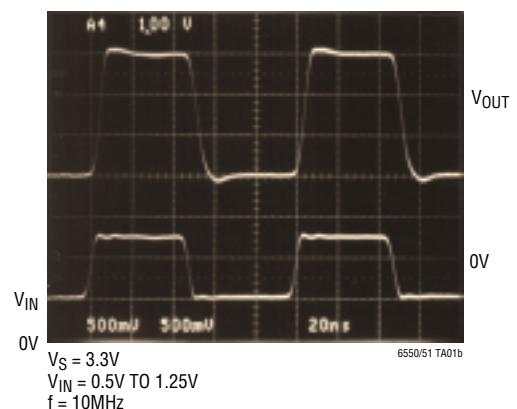
Both the LT6550 and LT6551 are available in the small 10-Pin MSOP package and utilize a flow-thru pin out. The small footprint, results in a compact high performance video amplifier solution.

TYPICAL APPLICATION

3.3V Single Supply RGB Plus SYNC Cable Driver



Output Step Response



65501i

LT6550/LT6551

ABSOLUTE MAXIMUM RATINGS

(Note 1)

Total Supply Voltage

LT6550 (V_{CC} TO V_{EE}) 12.6V

LT6551 (V_{CC} TO GND) 12.6V

Input Current (Note 9) $\pm 10\text{mA}$

Output Short-Circuit Duration (Note 2) Indefinite

Operating Temperature Range -40°C to 85°C

Specified Temperature Range (Note 3)

LT6550C/LT6551C 0°C to 70°C

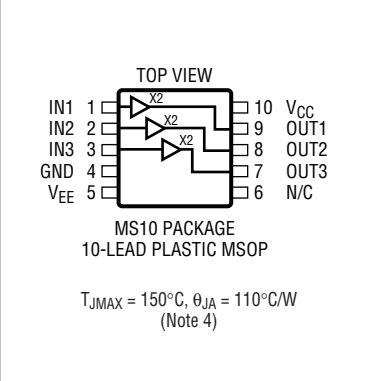
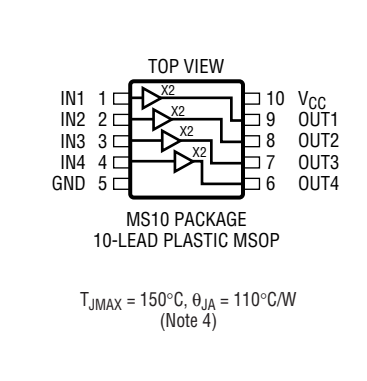
LT6550I/LT6551I -40°C to 85°C

Maximum Junction Temperature 150°C

Storage Temperature Range -65°C to 150°C

Lead Temperature (Soldering, 10 sec) 300°C

PACKAGE/ORDER INFORMATION

	ORDER PART NUMBER		ORDER PART NUMBER
	LT6550CMS LT6550IMS		LT6551CMS LT6551IMS
	MS10 PART MARKING		MS10 PART MARKING
	LTB9 LTC1		LTC2 LTC3

Consult LTC Marketing for parts specified with wider operating temperature ranges.

3.3V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^{\circ}\text{C}$. $V_{CC} = 3.3\text{V}$, $V_{GND} = 0\text{V}$; $V_{IN} = 0.75\text{V}$ LT6550 (Pins 1,2,3); LT6551 (Pins 1,2,3,4). $V_{EE} = 0\text{V}$ LT6550 (Pin 5), unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
DC Output Accuracy	No Load, V_{OUT} Ideal = 1.5V	● -70		70	mV
Output Matching	Between Any Two Outputs	●	25	75	mV
Input Current	Any Input	●	15	65	μA
Input Impedance, $\Delta V_{IN}/\Delta I_{IN}$	$V_{IN} = 0\text{V}$ to 1V	●	100	300	$\text{k}\Omega$
Voltage Gain (Note 5)	$0.25\text{V} \leq V_{IN} \leq 1.25\text{V}$				
	No Load	●	1.9	2.1	V/V
	$R_L = 150\Omega$	●	1.9	2.1	V/V
	$R_L = 75\Omega$, $0.25\text{V} \leq V_{IN} \leq 0.75\text{V}$		1.85	2.15	V/V
Output Voltage Swing Low	$V_{IN} = -0.1\text{V}$				
	No Load	●	10	30	mV
	$I_{SINK} = 5\text{mA}$	●	60	150	mV
	$I_{SINK} = 10\text{mA}$	●	90	200	mV
Output Voltage Swing High	$V_{IN} = 1.75\text{V}$				
	No Load	●	3.0	3.2	V
	$R_L = 150\Omega$	●	2.5	2.9	V
	$R_L = 75\Omega$		2.0	2.5	V

65501i

3.3V ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_{CC} = 3.3\text{V}$, $V_{GND} = 0\text{V}$; $V_{IN} = 0.75\text{V}$ LT6550 (Pins 1,2,3); LT6551 (Pins 1,2,3,4). $V_{EE} = 0\text{V}$ LT6550 (Pin 5), unless otherwise noted.

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
PSRR	$V_{CC} = 3\text{V to }10\text{V}$, $V_{IN} = 0.5\text{V}$	●	40	48		dB
Minimum Supply Voltage (Note 6)		●	3			V
Output Short-Circuit Current	$V_{IN} = 1\text{V}$, $V_{OUT} = 0\text{V}$	●	35 25	50		mA mA
Supply Current per Amplifier (Note 7)		●		8	10 11	mA mA
Slew Rate (Note 8)	$R_L = 150\Omega$, $V_{OUT} = 0.5\text{V to }2.5\text{V}$ Measured from 1V to 2V	●	140 115	250		V/ μs V/ μs
Small Signal -3dB Bandwidth	$R_L = 150\Omega$			90		MHz
Gain Flatness	Less than 0.25dB			30		MHz
Gain Matching	Any One Channel to Any Other Channel			0.15		dB
Settling Time to 3%	$R_L = 150\Omega$, 1.5V Output Step			20		ns
% Overshoot	$V_{OUT} = 1.5\text{V Step}$, $R_L = 150\Omega$			5		%
Channel Separation	Measured at 10MHz			60		dB

5V ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_{CC} = 5\text{V}$, $V_{GND} = 0\text{V}$; $V_{IN} = 1.25\text{V}$ LT6550 (Pins 1,2,3); LT6551 (Pins 1,2,3,4). $V_{EE} = 0\text{V}$ LT6550 (Pin 5), unless otherwise noted.

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Output Accuracy	No Load, V_{OUT} Ideal = 2.5V	●	-70		70	mV
Output Matching	Between Any Two Outputs	●		40	90	mV
Input Current		●		15	65	μA
Input Impedance, $\Delta V_{IN}/\Delta I_{IN}$	$V_{IN} = 0\text{V to }2\text{V}$	●	100	300		k Ω
Voltage Gain (Note 5)	$0.25\text{V} \leq V_{IN} \leq 1.75\text{V}$ No Load $R_L = 150\Omega$ $R_L = 75\Omega$, $0.25\text{V} \leq V_{IN} \leq 1.25\text{V}$, $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	● ● ●	1.9 1.9 1.85		2.1 2.1 2.15	V/V V/V V/V
Output Voltage Swing Low	$V_{IN} = -0.1\text{V}$ No Load $I_{SINK} = 5\text{mA}$ $I_{SINK} = 10\text{mA}$	● ● ●		10 60 90	30 150 200	mV mV mV
Output Voltage Swing High	$V_{IN} = 2.6\text{V}$ No Load $R_L = 150\Omega$ $R_L = 75\Omega$, $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	● ● ●	4.6 3.5 2.5	4.8 4.1 3.2		V V V
PSRR	$V_{CC} = 3\text{V to }10\text{V}$, $V_{IN} = 0.5\text{V}$	●	40	48		dB
Minimum Supply Voltage (Note 6)		●	3			V
Output Short-Circuit Current	$V_{IN} = 1\text{V}$, $V_{OUT} = 0\text{V}$ $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$ $-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	● ● ●	45 40 30	60		mA mA mA
Supply Current per Amplifier (Note 7)		●		9.5	11.5 12.5	mA mA

5V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_{CC} = 5\text{V}$, $V_{GND} = 0\text{V}$; $V_{IN} = 1.25\text{V}$ LT6550 (Pins 1,2,3); LT6551 (Pins 1,2,3,4). $V_{EE} = 0\text{V}$ LT6550 (Pin 5), unless otherwise noted.

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Slew Rate	$R_L = 150\Omega$, $V_{OUT} = 0\text{V}$ to 3.5V , Measured from 1V to 3V	●	220 180	340		$\text{V}/\mu\text{s}$ $\text{V}/\mu\text{s}$
Small Signal -3dB Bandwidth	$R_L = 150\Omega$			110		MHz
Gain Flatness	Less than 0.25dB			30		MHz
Gain Matching	Any One Channel to Any Other Channel			0.15		dB
Settling Time to 3%	$R_L = 150\Omega$, 1.5V Output Step			20		ns
% Overshoot	$V_{OUT} = 1.5\text{V}$ Step, $R_L = 150\Omega$			5		%
Channel Separation	Measured at 10MHz			60		dB

±5V ELECTRICAL CHARACTERISTICS (LT6550 Only)

The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = \pm 5\text{V}$, $V_{IN} = 0\text{V}$ (Pins 1,2,3) $V_{GND} = 0\text{V}$ (Pin 4) unless otherwise noted.

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Output Offset		●		30	70	mV
Output Matching	Between Any Two Outputs	●		20	60	mV
Input Current		●		20	70	μA
Input Impedance, $\Delta V_{IN}/\Delta I_{IN}$	$V_{IN} = -1\text{V}$ to 1V	●	200	500		k Ω
Voltage Gain	$-1.75\text{V} \leq V_{IN} \leq 1.75\text{V}$ No Load	●			2.1	V/V
	$R_L = 150\Omega$	●	1.9		2.1	V/V
	$R_L = 75\Omega$, $-1\text{V} \leq V_{IN} \leq 1\text{V}$	●	1.9		2.1	V/V
Output Voltage Swing	$V_{IN} = \pm 2.6\text{V}$ No Load	●	± 4.6	± 4.8		V
	$R_L = 150\Omega$	●	± 3.5	± 4.2		V
	$R_L = 75\Omega$, $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	●	± 2.6	± 3.2		V
PSRR	$V_S = \pm 2.5\text{V}$ to $\pm 5\text{V}$,	●	38	48		dB
Output Short-Circuit Current	$V_O = 0\text{V}$		45	60		mA
	$0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	●	40			mA
	$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	●	30			mA
Supply Current per Amplifier		●		8.5	10.5 12	mA mA
Slew Rate	$R_L = 150\Omega$, $V_{OUT} = -3\text{V}$ to 3V , Measured from -2V to 2V		400	500		$\text{V}/\mu\text{s}$
		●	300			$\text{V}/\mu\text{s}$
Small Signal -3dB Bandwidth	$R_L = 150\Omega$			90		MHz
Gain Flatness	Less than 0.25dB			30		MHz
Gain Matching	Any One Channel to Any Other Channel			0.15		dB
Settling Time to 3%	$R_L = 150\Omega$, 1.5V Output Step			20		ns
% Overshoot	$V_{OUT} = 1.5\text{V}$ Step, $R_L = 150\Omega$			5		%
Channel Separation	Measured at 10MHz			60		dB

ELECTRICAL CHARACTERISTICS

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: A heat sink may be required to keep the junction temperature below absolute maximum. This depends on the power supply voltage and how many amplifiers are shorted.

Note 3: The LT6550C/LT6551C are guaranteed to meet specified performance from 0°C to 70°C and are designed, characterized and expected to meet specified performance from -40°C to 85°C but are not tested or QA sampled at these temperatures. The LT6550I/LT6551I are guaranteed to meet specified performance from -40°C to 85°C.

Note 4: Thermal resistance varies depending upon the amount of PC board metal attached to Pin 5 of the device. θ_{JA} is specified for a 2500mm² test board covered with 2oz copper on both sides.

Note 5: Gain is measured by changing the input voltage, and dividing the change in output voltage by the change in input voltage.

Note 6: Minimum supply voltage is guaranteed by the PSRR test.

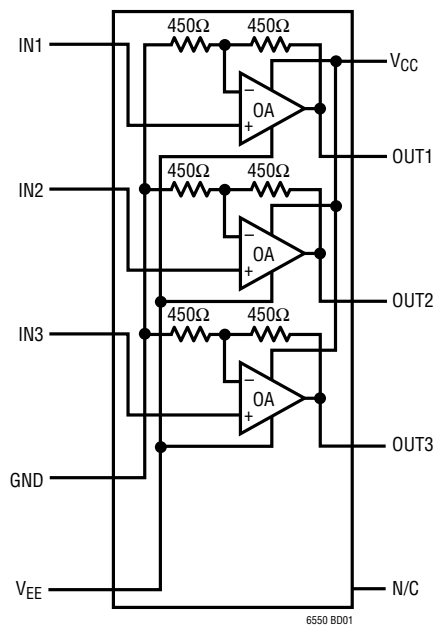
Note 7: The supply current specification includes additional output current through the internal feedback and gain resistor.

Note 8: Guaranteed by correlation to slew rate at 5V and $\pm 5V$.

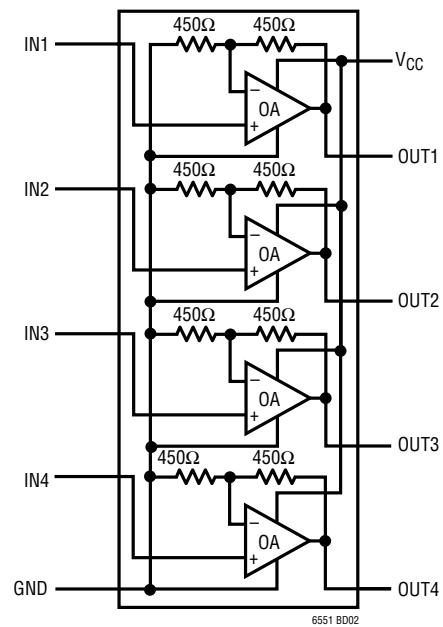
Note 9: The inputs are protected from ESD with diodes to the supplies.

BLOCK DIAGRAMS

LT6550 Block Diagram



LT6551 Block Diagram



APPLICATIONS INFORMATION

Amplifier Characteristics

Figure 1 shows a simplified schematic of one channel of the LT6551 quad. Resistors R_F and R_G provide an internal gain of 2. (The LT6550 triple is a slight variation with the gain setting resistor, R_G , connected to a separate ground pin). The input stage consists of transistors Q1 to Q8 and resistor R1. This topology allows for high slew rates at low supply voltages. There are back-to-back series diodes, D1 to D4, across the + and – inputs of each amplifier to limit the differential input voltage to $\pm 1.4V$. R_{IN} limits the current through these diodes if the input differential voltage exceeds $\pm 1.4V$. The input stage drives the degeneration resistors of PNP and NPN current mirrors, Q9 to Q12, that convert the differential signals into a single-ended output. The differential drive generator supplies current to the output transistors that swing from rail-to-rail.

Input Voltage Range

The input voltage range is V_{EE} to $(V_{CC} - 1.75V)$ over temperature. If the device is operated on a single 3V supply

the maximum input is $(3V - 1.75V)$ or 1.25V, and the internal gain of two will set the output voltage to 2.5V. Increasing the input beyond 1.25V will force the device out of its linear range, no longer a gain of 2, and the output will not increase beyond 2.5V. At a higher supply voltage, i.e. 5V, the maximum input voltage is $5V - 1.75V$ or 3.25V. However, due to the internal gain of 2, the output will clip with a lower input voltage. For linear unclipped operation the minimum input voltage is $(V_{OUT\ Min})/2$ and the maximum input voltage is $(V_{OUT\ Max})/2$ or $(V_{CC} - 1.75V)$, whichever is less.

ESD

The LT6550/LT6551 have reverse-biased ESD protection diodes on all inputs and outputs as shown in Figure 1. If these pins are forced beyond either supply, unlimited current will flow through these diodes. If the current is limited to 10mA or less, no damage to the device will occur.

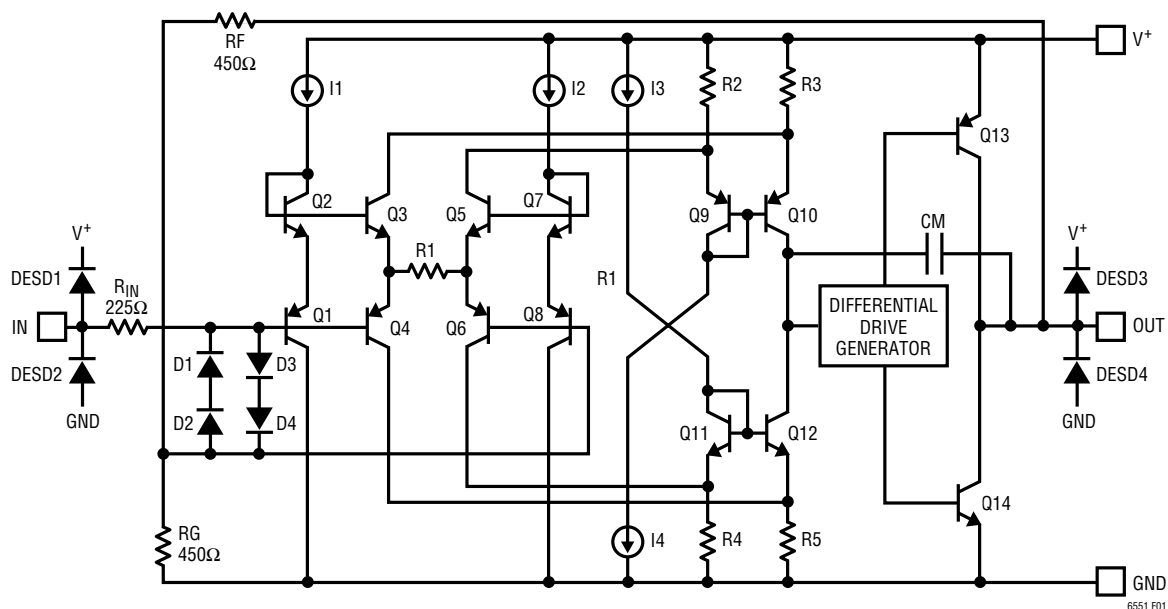
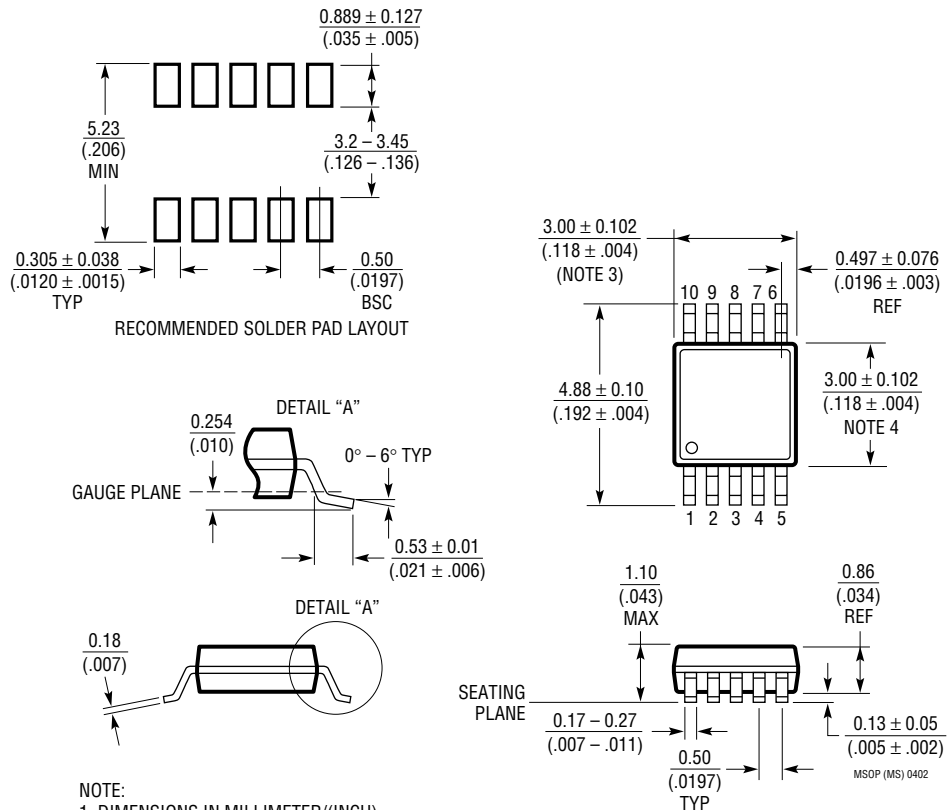


Figure 1. LT6551 Simplified Schematic

PACKAGE DESCRIPTION

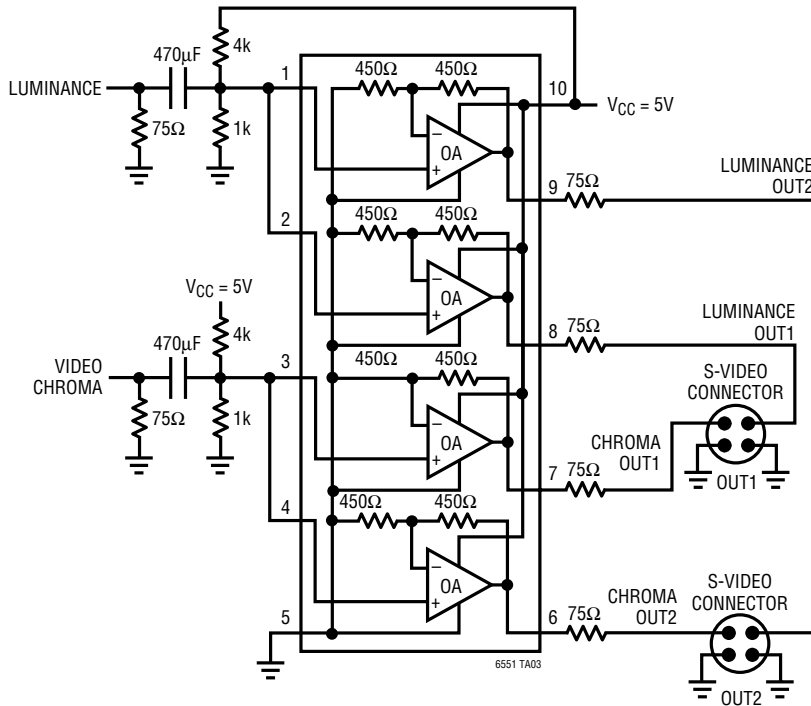
MS Package
10-Lead Plastic MSOP
 (Reference LTC DWG # 05-08-1661)



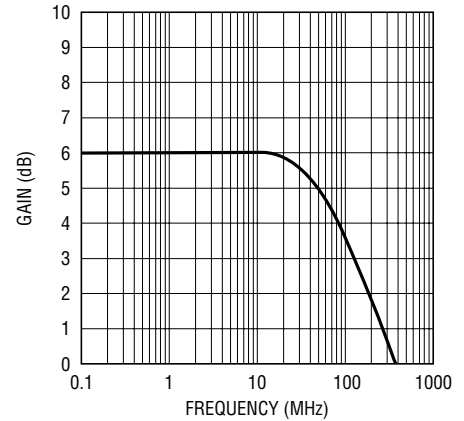
- NOTE:
1. DIMENSIONS IN MILLIMETER/(INCH)
 2. DRAWING NOT TO SCALE
 3. DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
 4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
 5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX

TYPICAL APPLICATION

S Video Splitter



Gain vs Frequency



6550/51 TA02

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1259/LT1260	Dual/Triple 130MHz Current Feedback Amplifiers	Shutdown, Operates to ±15V
LT1395/LT1396/LT1397	Single, Dual, Quad 400MHz Current Feedback Amplifier	800V/µs Slew Rate
LT1398/LT1399	Dual/Triple 300MHz Current Feedback Amplifier	0.1dB Gain Flatness to 150MHz, Shutdown
LT1675/LT1675-1	250MHz, Triple and Single RGB Multiplexer with Current Feedback Amplifiers	100MHz Pixel Switching, -3dB Bandwidth: 250MHz, 1100V/µs Slew Rate
LT1809/LT1810	Single/Dual, 180MHz, Rail-to-Rail Input and Output Amplifiers	350V/µs Slew Rate, Shutdown, Low Distortion -90dBc at 5MHz